



# ENGINEERING PHYSICS

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# ENGINEERING PHYSICS

## Unit III : Application of Quantum Mechanics to Electrical transport in Solids

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### ➤ *Suggested Reading*

1. *Fundamentals of Physics, Resnik and Halliday, Chapter 41*
2. *Concepts of Modern Physics, Arthur Beiser, Chapter 9*
3. *Learning material prepared by the department- Unit III*

### ➤ *Reference Videos*

1. [Physics Of Materials-IIT-Madras/lecture-07.html](https://www.youtube.com/watch?v=...)

# ENGINEERING PHYSICS

## Unit III : Application of Quantum Mechanics to Electrical transport in Solids

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### *Class #23*

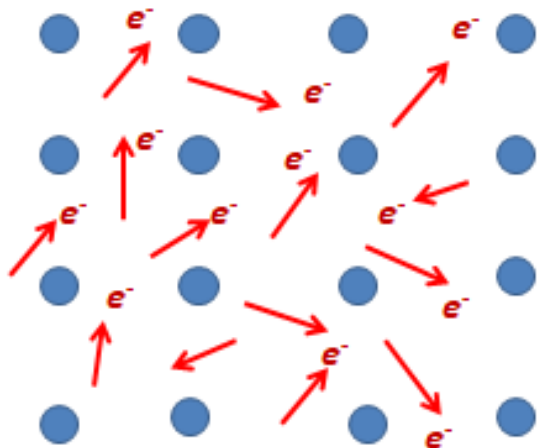
- *Features of classical free electron model*
- *Expression for electrical conductivity*
- *Failures of classical free electron theory*

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## Features of classical free electron model

*Drude and Lorentz proposed the classical free electron theory of electrical conductivity of metals in 1900*

- *Valence electrons- treated as conduction electrons*
- *Electrostatic interaction- neglected*
- *Electrons in the metal– treated as free electron gas*
- *Free-electron gas- follows Maxwell-Boltzmann statistics*



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## Thermal Velocity

*Thermal energy of the free electrons in the absence of the electric field is given by*

$$\frac{1}{2}mv_{th}^2 = \frac{3}{2}kT$$

*Therefore average thermal velocity*  $v_{th} = \sqrt{\frac{3k_B T}{m}}$

- *Random motion of the electrons do not contribute to a net drift of electrons.*
- *no current flows through the material*

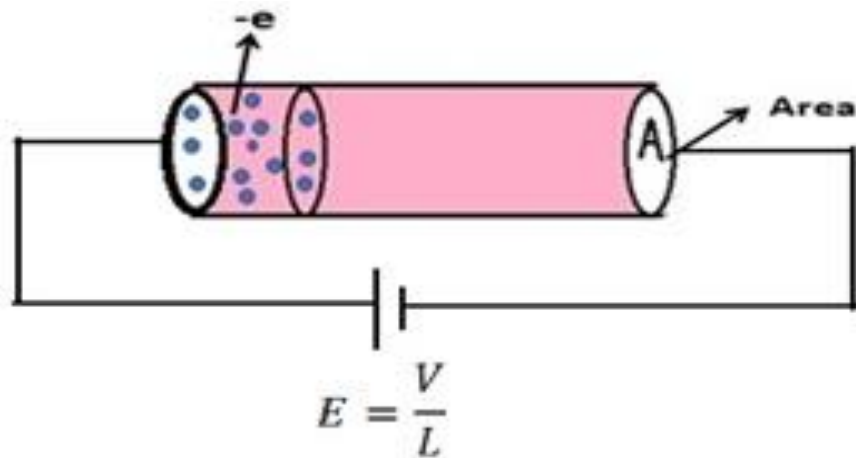
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## Drift Velocity

*Under the influence of electric field  $E$  the average velocity experienced by the electrons is called drift velocity*

$$v_d = \frac{e\tau E}{m} = \mu E$$

*Where  $\mu = \frac{e\tau}{m} = \frac{v_d}{E}$  is the drift velocity per unit electric field*



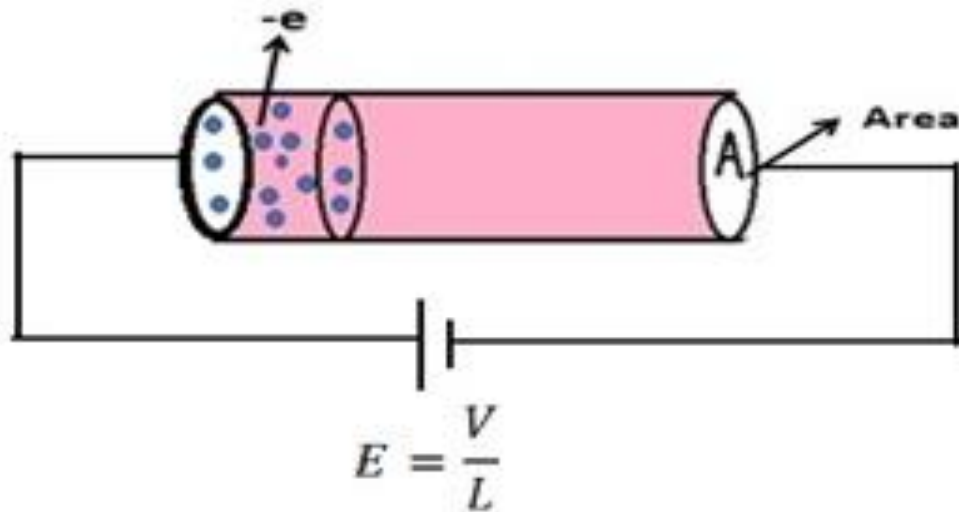
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## Expression for electrical conductivity

The current through a conductor  $I = nev_d A$

Where  $v_d$  is the drift velocity given by  $v_d = \frac{e\tau E}{m}$

$$\therefore I = neA \frac{e\tau E}{m}$$



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## Expression for electrical conductivity

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$$J = \frac{I}{A} = \frac{ne^2\tau}{m} E = \sigma E$$

*where  $\sigma$  is a constant for a given metal*

$$\sigma = \frac{ne^2\tau}{m} = ne\mu$$

*The resistivity of the metal is given by*

$$\rho = \frac{1}{\sigma} = \frac{m}{ne^2\tau} = \frac{1}{ne\mu}$$



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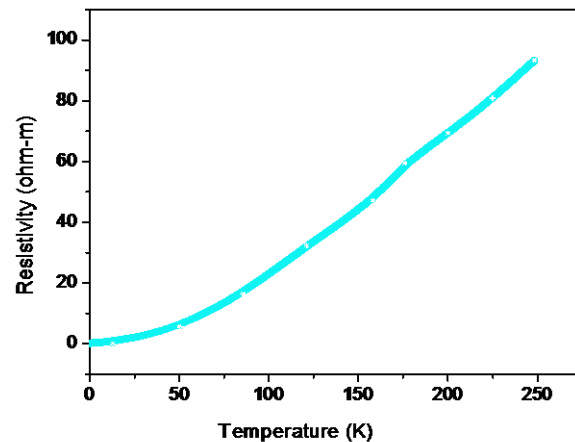
## Experimental temperature dependence of resistivity

Total resistivity of the metal is given by  $\rho = \rho_i + \rho_{sc}$

Substituting the value of  $\rho$  we get  $\frac{m}{ne^2\tau} = \frac{m}{ne^2\tau_{res}} + \frac{m}{ne^2\tau_{sc}}$

This relation is called Mattheissen's rule

This gives the effective relaxation time  $\frac{1}{\tau} = \frac{1}{\tau_{res}} + \frac{1}{\tau_{sc}}$



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## *Failures of classical free electron theory*

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- *Temperature dependence of resistivity*
- *Specific heat of electrons in a metal*
- *Conductivity variations with electron concentrations*

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## Temperature dependence of resistivity



According to CFET resistivity is given by  $\rho = \frac{m}{ne^2\tau}$

Temperature dependence of the relaxation time  $\tau = \frac{\lambda}{v_{th}}$

For a given temperature  $v_{th} = \sqrt{\frac{3k_B T}{m}}$

Hence  $v_{th} \propto \sqrt{T}$  or  $\tau \propto T^{-\frac{1}{2}}$

Since the resistivity  $\rho \propto \frac{1}{\tau} \therefore \rho \propto \sqrt{T}$

According to experimental observations  $\rho \propto T$

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## Specific heat of electrons in a metal

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*Specific heat of the metal is  $C_{el} = \frac{dU}{dT}$*

*For one mole of a mono-valent metal  $U = \frac{3}{2} k_B T \cdot N_A$*

*Hence the specific heat of the electrons*

$$C_{el} = \frac{dU}{dT} = \frac{3}{2} k_B \cdot N_A = \frac{3}{2} R$$

*Experimental estimation of the specific heat of electrons is  
 $\approx 1\%$  of the theoretical values*

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## Conductivity variations with electron concentrations

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$$\sigma = \frac{ne^2\tau}{m}$$

*Free electron concentration of copper and aluminum is  $8.4 \times 10^{28}/\text{m}^3$  and  $18.1 \times 10^{28}/\text{m}^3$*

$$n_{\text{cu}} < n_{\text{Al}}$$

*Conductivity of copper and aluminum at  $20^\circ\text{C}$  is  $5.9 \times 10^7 \text{ S/m}$  and  $3.5 \times 10^7 \text{ S/m}$*

$$\sigma_{\text{cu}} > \sigma_{\text{Al}}$$

*Copper with lesser electronic concentration has a higher electrical conductivity as compared to trivalent Aluminum.*

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## Class 23 . Quiz ...

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The concepts which are correct are....

1. *Drude model treats the free electrons equivalent to molecules in a gas*
2. *The distribution of energy and velocity is assumed to follow Maxwell-Boltzmann statistics*
3. *The drift velocity of the electron is due to the application thermal energy*
4. *The resistivity in metal due to impurities dependent on temperature*
5. *The classical free electron theory explains the electronic specific heat ( $C_v$ ) of solid*



## THANK YOU

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